Monolithic Amplifier

0.05-1 GHz

Product Features

- Similar to Agilent MSA-1105 and Mini-Circuits MAV-11SM+
- High IP3, 34 dBm typ.
- Excellent VSWR, 1.2:1 typ.
- Medium gain
- Output power, 18 dBm typ.
- Aqueous washable

Typical Applications

- Cellular
- UHF/VHF receivers/transmitters



MAV-11BSM+

CASE STYLE: RRR137 PRICE: \$1.50 ea. QTY. (30)

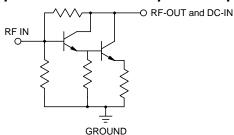
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

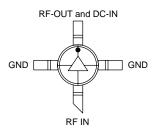
The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

General Description

MAV-11BSM+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a plastic molded package. MAV-11BSM+ uses Darlington configuration and is fabricated using silicon technology. Expected MTBF is 270 years at 85°C case temperature.

simplified schematic and pin description





Function	Pin Number	Description
RF IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.





Electrical Specifications at 25°C and 60mA, unless noted

Parameter		Min.	Тур.	Max.	Units
Frequency Range*		0.05		1	GHz
Gain	f=0.1 GHz		12.7		dB
	f=1 GHz	9.5 ²	11.3		
	f=2 GHz		9.5		
Input Return Loss	f=0.05 to 1 GHz		21		dB
Output Return Loss	f=0.05 to 1 GHz		21		dB
Output Power @ 1 dB compression	f=1 GHz		+18		dBm
Output IP3	f=1 GHz		+34		dBm
Noise Figure	f=1 GHz		4.4		dB
Recommended Device Operating Current			60		mA
Device Operating Voltage			5.5		V
Thermal Resistance, junction-to-case ¹			141		°C/W

^{*}Guaranteed specification 0.05-1 GHz. Low frequency cut off determined by external coupling capacitors.

Absolute Maximum Ratings

Parameter	Ratings	
Operating Temperature	-40°C to 85°C	
Storage Temperature	-55°C to 100°C	
Operating Current	80mA	
Power Dissipation	460mW	
Input Power	13dBm	

Note: Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

¹Case is defined as ground leads.

²Full temperature range.





Product Marking



Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: RRR137

Plastic molded package, .145 body diameter, lead finish: tin/silver/nickel

Tape & Reel: F11

Suggested Layout for PCB Design: PL-169

Evaluation Board: TB-412-11B+

Environmental Ratings: ENV08T3

Recommended Application Circuit

R BIAS				
Vcc	"1%" Res. Values (ohms) for Optimum Biasing			
7	28.0			
8	45.3			
9	61.9			
10	78.7			
11	95.3			
12	113			
13	127			
14	143			
15	158			





ESD Rating

Human Body Model (HBM): Class 1B (500 v to < 1000 v) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (< 100 v) in accordance with ANSI/ESD STM 5.2 - 1999

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	J-Std-020C (Jedec Standard)	45 units
4	Moisture Sensitivity Level 1	Bake at 125°C for 24 hours Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-Std-020C (Jedec Standard)	45 units

MSL Test Flow Chart

